

Electrical Characteristics @ Tj = 25°C (Unless Otherwise Specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
BV _{DSS}	Drain-to-Source Breakdown Voltage	500			V	$V_{GS} = 0V, I_{D} = 1.0mA$	
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient		0.43		V/°C	Reference to 25°C, I _D = 1.0mA	
R _{DS(on)}	Static Drain-to-Source On-Resistance			3.0	Ω	V _{GS} = 10V, I _{D2} = 1.0A ④	
				3.1		V _{GS} = 10V, I _{D1} = 1.5A ④	
$V_{GS(th)}$	Gate Threshold Voltage	2.0		4.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Gfs	Forward Transconductance	1.0			S	V _{DS} = 15V, I _{D2} = 1.0A ④	
I _{DSS}	Zoro Coto Voltago Drain Current			25		$V_{DS} = 400 \text{ V}, V_{GS} = 0 \text{V}$	
	Zero Gate Voltage Drain Current			250	μA	$V_{DS} = 400V, V_{GS} = 0V, T_{J} = 125^{\circ}C$	
I_{GSS}	Gate-to-Source Leakage Forward			100	nA	V _{GS} = 20V	
	Gate-to-Source Leakage Reverse			-100	IIA	V _{GS} = -20V	
Q_G	Total Gate Charge	7.3		25		I _{D1} = 1.5A	
Q_{GS}	Gate-to-Source Charge	0.1		6.0	nC	V _{DS} = 250V	
Q_{GD}	Gate-to-Drain ('Miller') Charge	3.7		18		V _{GS} = 10V	
$t_{d(on)}$	Turn-On Delay Time			40		$V_{DD} = 225V$	
tr	Rise Time			30	20	$I_{D1} = 1.5A$ $R_G = 7.5\Omega$	
$t_{d(off)}$	Turn-Off Delay Time			60	ns		
t _f	Fall Time			30		V _{GS} = 10V	
Ls +L _D	Total Inductance		7.0		nH	Measured from Drain lead (6mm / 0.25 i from package) to Source lead (6mm/ 0.2 in from package) with Source wire internally bonded from Source pin to Drapin	
C _{iss}	Input Capacitance		350			V _{GS} = 0V	
C _{oss}	Output Capacitance		80		pF	V _{DS} = 25V	
C _{rss}	Reverse Transfer Capacitance		35			f = 1.0MHz	

Source-Drain Diode Ratings and Characteristics

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Is	Continuous Source Current (Body Diode)			1.5	^	
I _{SM}	Pulsed Source Current (Body Diode) ①			6.0	A	
V_{SD}	Diode Forward Voltage			1.2	V	$T_J = 25^{\circ}C, I_S = 1.5A, V_{GS} = 0V$
t _{rr}	Reverse Recovery Time			900	ns	$T_J = 25^{\circ}C, I_F = 1.5A, V_{DD} \le 50V$
Q _{rr}	Reverse Recovery Charge			5.9	μC	di/dt = 100A/µs ④
t _{on}	Forward Turn-On Time	Intrinsic turn-on time is negligible (turn-on is dominated by L_S+L_D)				

Thermal Resistance

Symbol	Parameter	Min.	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case			6.25	°CAM
$R_{\theta JA}$	Junction-to-Ambient (Typical Socket Mount)			175	°C/W

Footnotes:

- ① Repetitive Rating; Pulse width limited by maximum junction temperature.
- $^{\circ}$ V_{DD} = 50V, starting T_J = 25°C, L = 100 μ H, Peak I_L = 2.2A
- $\label{eq:local_spin_spin} \ \, I_{SD} \leq 1.5 A, \, di/dt \leq 50 A/\mu s, \, V_{DD} \leq 500 V, \, T_J \leq 150^{\circ} C, \, Suggested \,\, R_G = 7.5 \,\, \Omega$
- 4 Pulse width $\leq 300 \ \mu s$; Duty Cycle $\leq 2\%$

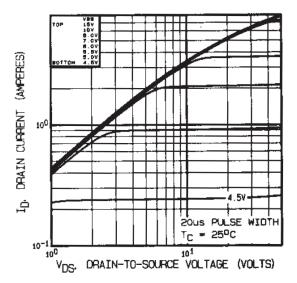


Fig 1. Typical Output Characteristics

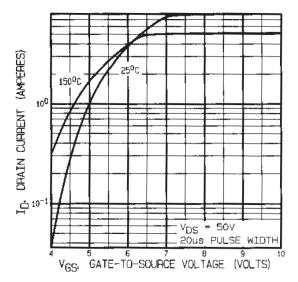


Fig 3. Typical Transfer Characteristics

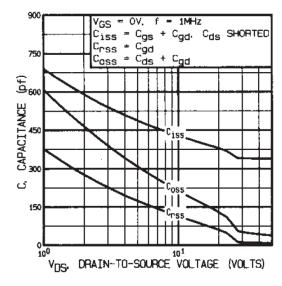


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

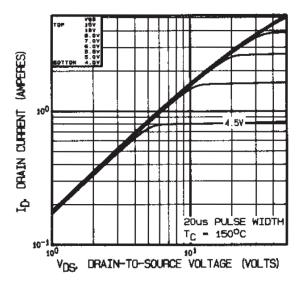


Fig 2. Typical Output Characteristics

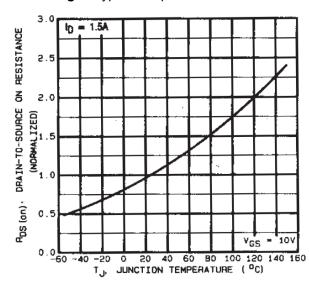


Fig 4. Normalized On-Resistance Vs. Temperature

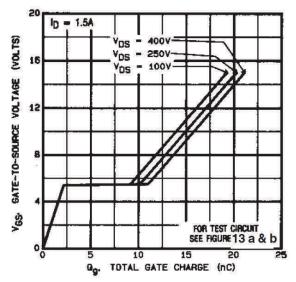


Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

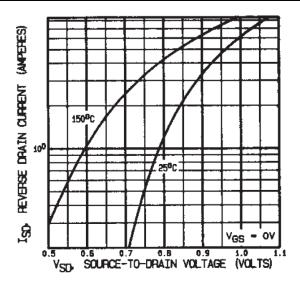


Fig 7. Typical Source-Drain Diode Forward Voltage

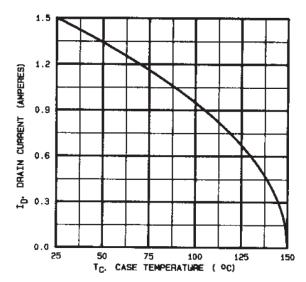


Fig 9. Maximum Drain Current Vs. Case Temperature

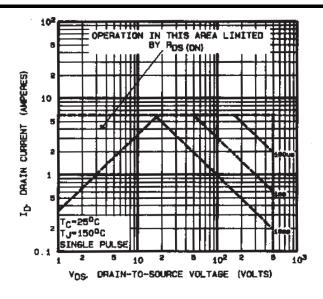


Fig 8. Maximum Safe Operating Area

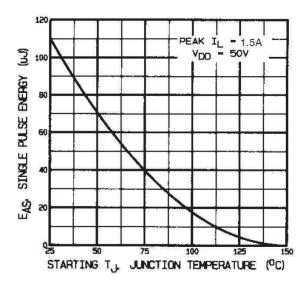


Fig 10. Maximum Avalanche Energy Vs. Drain Current

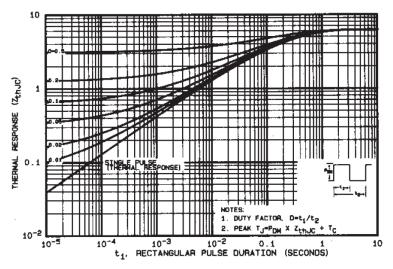


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case

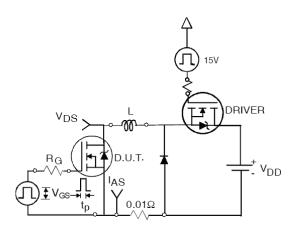


Fig 12a. Unclamped Inductive Test Circuit

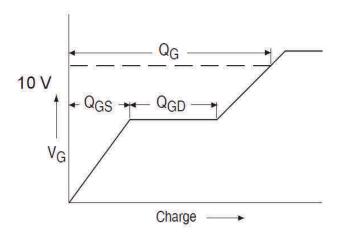


Fig 13a. Gate Charge Waveform

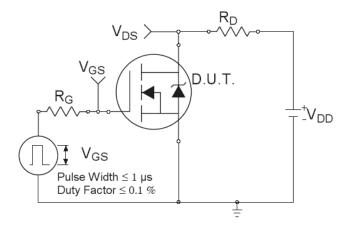


Fig 14a. Switching Time Test Circuit

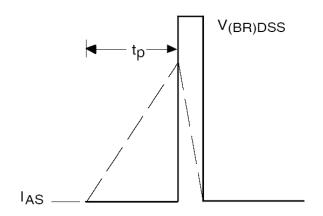


Fig 12b. Unclamped Inductive Waveforms

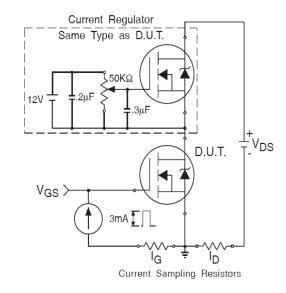


Fig 13b. Gate Charge Test Circuit

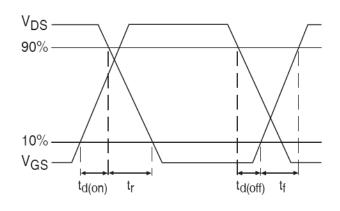
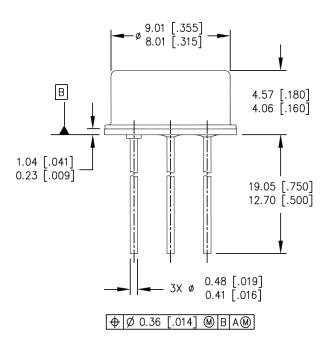


Fig 14b. Switching Time Waveforms



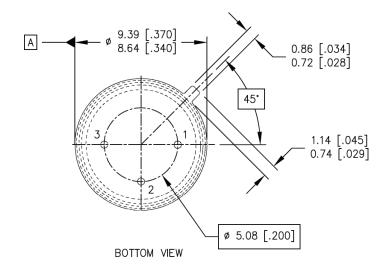
Case Outline and Dimensions - TO-205AF (TO-39)



NOTES: SIDE VIEW

1. DIMENSIONING AND TOLERANCING PER ASME 14.5M-1994.

- 2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
- 3. CONTROLLING DIMENSION: INCH.
- 4. CONFORMS TO JEDEC OUTLINE TO-205AF (TO-39).



LEGEND

1- SOURCE

2- GATE

3- DRAIN (CONNECTED TO THE CASE)



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Data and specifications subject to change without notice.



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